2-input OR Gate

REJ03D0187-0500Z (Previous ADE-205-313C (Z)) Rev.5.00 Jan.27.2004

Description

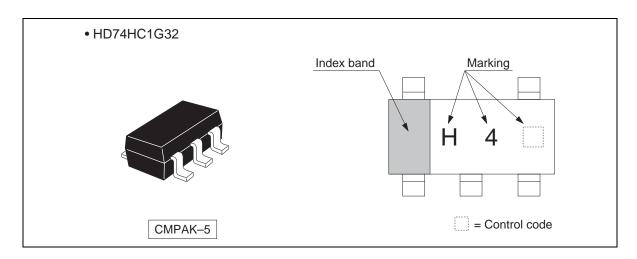
The HD74HC1G32 is high speed CMOS two input OR gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high-speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output.

Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Electrical characteristics equivalent to the HD74HC32 Supply voltage range: 2 to 6 V
 Operating temperature range: -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$
- Ordering Information

| Part Name | Package Type | Package Code | Package Abbreviation | Taping Abbreviation (Quantity) |
|---------------|--------------|--------------|-------------------------|--------------------------------|
| HD74HC1G32CME | CMPAK-5 pin | CMPAK-5V | CM | E (3,000 pcs/reel) |

Outline and Article Indication



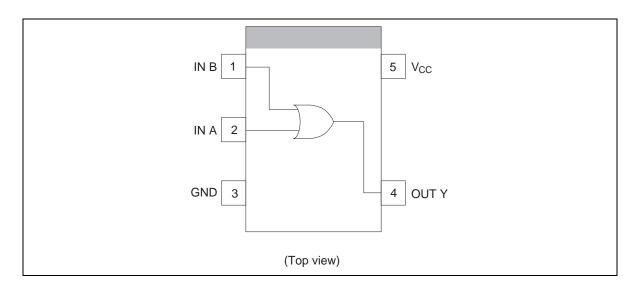
Function Table

Inputs

| A | В | Output Y |
|---|---|----------|
| L | L | L |
| Н | L | Н |
| L | Н | Н |
| Н | Н | Н |

H : High level L : Low level

Pin Arrangement



Absolute Maximum Ratings

| Item | Symbol | Ratings | Unit | Test Conditions |
|--|-------------------------------------|-------------------------------|------|-----------------------------|
| Supply voltage range | V _{CC} | –0.5 to 7.0 | V | |
| Input voltage range *1 | Vı | -0.5 to V _{CC} + 0.5 | V | |
| Output voltage range *1, 2 | Vo | -0.5 to V _{CC} + 0.5 | V | Output : H or L |
| Input clamp current | I _{IK} | ±20 | mA | $V_I < 0$ or $V_I > V_{CC}$ |
| Output clamp current | I _{OK} | ±20 | mA | $V_O < 0$ or $V_O > V_{CC}$ |
| Continuous output current | Io | ±25 | mA | $V_{O} = 0$ to V_{CC} |
| Continuous current through V _{CC} or GND | I _{CC} or I _{GND} | ±25 | mA | |
| Maximum power dissipation at Ta = 25°C (in still air) *3 | P _T | 200 | mW | |
| Storage temperature | Tstg | -65 to 150 | °C | |

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

| Item | Symbol | Min | Max | Unit | Test Conditions |
|------------------------|---------------------------------|-----|-----------------|-------------|--------------------------|
| Supply voltage range | V _{CC} | 2 | 6 | V | |
| Input voltage range | Vı | 0 | V _{CC} | V | |
| Output voltage range | Vo | 0 | V _{CC} | V | |
| Output current | l _{OL} | _ | 2.0 | mA | $V_{CC} = 4.5 \text{ V}$ |
| | | _ | 2.6 | | $V_{CC} = 6.0 \text{ V}$ |
| | I _{OH} | _ | -2.0 | mA | $V_{CC} = 4.5 \text{ V}$ |
| | | _ | -2.6 | | $V_{CC} = 6.0 \text{ V}$ |
| Input rise / fall time | t _r , t _f | 0 | 1000 | ns | V _{CC} = 2.0 V |
| (10% to 90%) | | 0 | 500 | | $V_{CC} = 4.5 \text{ V}$ |
| | | 0 | 400 | | $V_{CC} = 6.0 \text{ V}$ |
| Operating temperature | Та | -40 | 85 | °C | |

Note: Unused or floating inputs must be held high or low.

Electrical Characteristics

| | | $\mathbf{V}_{\mathbf{CC}}$ | V_{CC} $T_a = 25^{\circ}C$ | | | $T_a = -4$ | 10 to 85°C | | | |
|-------------------|-----------------|----------------------------|------------------------------|------|------|------------|------------|------|------------------------------------|----------------------------|
| Item | Symbol | (V) | Min | Тур | Max | Min | Max | Unit | Test Con | ditions |
| Input voltage | V _{IH} | 2.0 | 1.5 | _ | _ | 1.5 | _ | V | | |
| | | 4.5 | 3.15 | _ | _ | 3.15 | _ | - | | |
| | | 6.0 | 4.2 | _ | _ | 4.2 | _ | = | | |
| | V _{IL} | 2.0 | _ | _ | 0.5 | _ | 0.5 | = | | |
| | | 4.5 | _ | _ | 1.35 | _ | 1.35 | = | | |
| | | 6.0 | _ | _ | 1.8 | _ | 1.8 | = | | |
| Output voltage | V _{OH} | 2.0 | 1.9 | 2.0 | _ | 1.9 | _ | V | V _{IN} = | $I_{OH} = -20 \mu A$ |
| | | 4.5 | 4.4 | 4.5 | _ | 4.4 | _ | = | V_{IH} or V_{IL} | |
| | | 6.0 | 5.9 | 6.0 | _ | 5.9 | | = | | |
| | | 4.5 | 4.18 | 4.31 | _ | 4.13 | _ | = | | $I_{OH} = -2 \text{ mA}$ |
| | | 6.0 | 5.68 | 5.80 | _ | 5.63 | _ | _ | | $I_{OH} = -2.6 \text{ mA}$ |
| | V _{OL} | 2.0 | _ | 0.0 | 0.1 | _ | 0.1 | = | | I _{OL} = 20 μA |
| | | 4.5 | _ | 0.0 | 0.1 | _ | 0.1 | = | | |
| | | 6.0 | _ | 0.0 | 0.1 | _ | 0.1 | = | | |
| | | 4.5 | _ | 0.17 | 0.26 | _ | 0.33 | = | | I _{OL} = 2 mA |
| | | 6.0 | _ | 0.18 | 0.26 | _ | 0.33 | = | | I _{OL} = 2.6 mA |
| Input current | I _{IN} | 6.0 | _ | _ | ±0.1 | _ | ±1.0 | μΑ | $V_{IN} = V_{CC}$ or GND | |
| Operating current | I _{CC} | 6.0 | _ | _ | 1.0 | _ | 10.0 | μΑ | $V_{IN} = V_{CC}$ | or GND |

Switching Characteristics

 $Ta = 25^{\circ}C$

| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
|-------------------------|--------------------------------------|-----|-----|-----|------|-----------------|
| Output rise / fall time | t _{TLH} t _{THL} | _ | 5 | 10 | ns | Test circuit |
| Propagation delay time | t _{PLH} t _{PHL} | _ | 7 | 15 | ns | Test circuit |

 $C_L = 15 \text{ pF}, t_r = t_f = 6 \text{ ns}, V_{CC} = 5 \text{ V}$

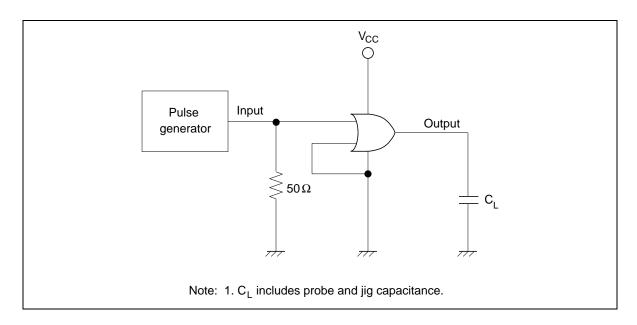
| | | \mathbf{V}_{CC} | Ta = 25°C | | Ta = -40 to 85°C | | | | |
|-------------------------|------------------|--------------------------|-----------|-----|------------------|-----|-----|------|-----------------|
| Item | Symbol | (V) | Min | Тур | Max | Min | Max | Unit | Test Conditions |
| Output rise / fall time | t _{TLH} | 2.0 | _ | 50 | 125 | _ | 155 | ns | Test circuit |
| | t_{THL} | 4.5 | _ | 14 | 25 | _ | 31 | | |
| | | 6.0 | _ | 12 | 21 | _ | 26 | _ | |
| Propagation delay time | t _{PLH} | 2.0 | _ | 48 | 100 | _ | 125 | ns | Test circuit |
| | t_{PHL} | 4.5 | _ | 12 | 20 | _ | 25 | _ | |
| | | 6.0 | _ | 9 | 17 | _ | 21 | _ | |
| Input capacitance | C _{IN} | _ | _ | 2.5 | 5 | _ | 5 | pF | |
| Equivalent capacitance | C _{PD} | _ | _ | 10 | _ | _ | | pF | |

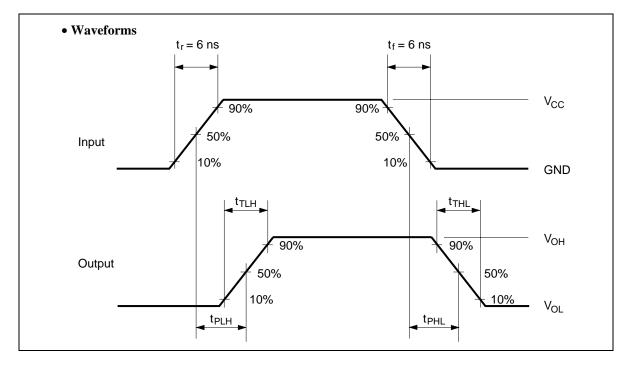
 $(C_L = 50 \text{ pF}, t_r = t_f = 6 \text{ ns})$

Note: C_{PD} is equivalent capacitance inside of the IC calculated from the operating current without load (see test circuit). The average operating current without load is calculated according to the expression

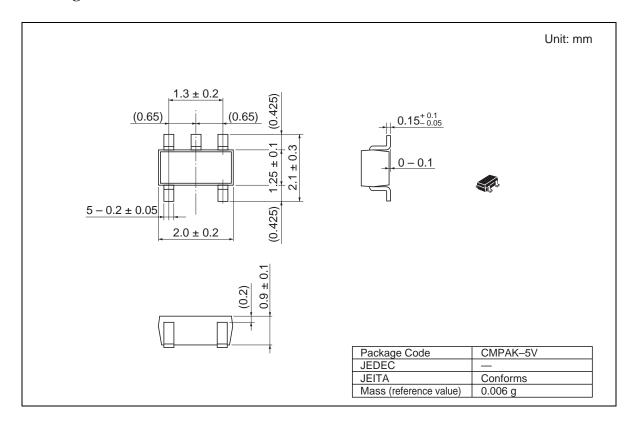
 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Test Circuit





Package Dimensions



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Renesas Technology Singapore Pte. Ltd.
1, Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

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